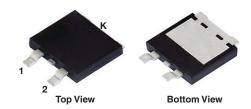
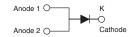


Ultrafast Rectifier, 16 A FRED Pt®

eSMP[®] Series SMPD (TO-263AC)



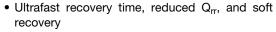


DESIGN SUPPORT TOOLS AVAILABLE



PRIMARY CHARACTERISTICS					
I _{F(AV)}	16 A				
V _R	600 V				
V _F at I _F	0.91 V				
t _{rr}	55 ns				
T _J max.	175 °C				
Package	SMPD (TO-263AC)				
Circuit configuration	Single				

FEATURES





RoHS

COMPLIANT **HALOGEN**

FREE

• 175 °C maximum operating junction temperature

• For PFC CRM, snubber operation

Low forward voltage drop

Low leakage current

• Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

- Meets JESD 201 class 2 whisker test
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		600	V
Average rectified forward current	I _{F(AV)}	T _{solder pad} = 141 °C	16	۸
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C, 6 ms square pulse	160	А

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Farment valters	V	I _F = 16 A	-	1.04	1.25	V	
Forward voltage	V _F	I _F = 16 A, T _J = 150 °C	-	0.91	1.1		
Deverage legisers overest		V _R = V _R rated	-	-	15		
Reverse leakage current I _R	I _R	T _J = 150 °C, V _R = V _R rated	-	70	300	μΑ	
Junction capacitance	C _T	V _R = 600 V	-	16	-	pF	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		I _F = 1 A, dI _F /dt = 50 A	õs, V _R = 30 V	-	55	-	
B		$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	55	
Reverse recovery time	t _{rr}	T _J = 25 °C	$I_F = 16 \text{ A},$ $dI_F/dt = 500 \text{ A/}\mu\text{s},$ $V_R = 400 \text{ V}$	-	100	-	ns
		T _J = 125 °C		-	150	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	20	-	Α
				27	-	_ ^	
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	1	-	
	T _J = 125 °C		-	2	-	μC	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C
Thermal resistance, junction to solder pad	R _{thJ-Sp}		-	1.2	1.7	°C/W
Approximate weight				0.55		g
Approximate weight				0.02		oz.
Marking device		Case style SMPD (TO-263AC)		16EI	DU06	

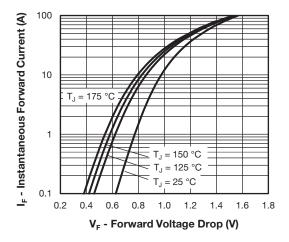


Fig. 1 - Typical Forward Voltage Drop Characteristics

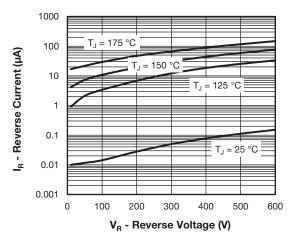


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

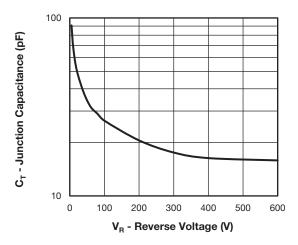


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

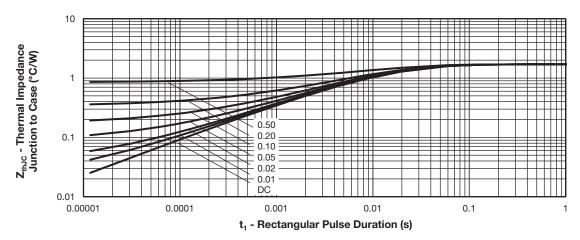


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

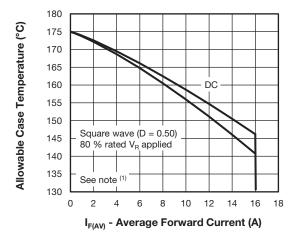
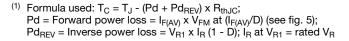


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current



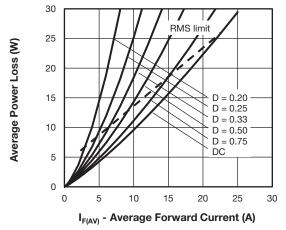
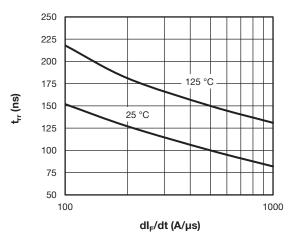


Fig. 6 - Forward Power Loss Characteristics



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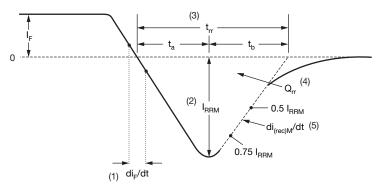
Vishay Semiconductors



2500 2000 2000 1500 1000 1000 1000 1000 1000

Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

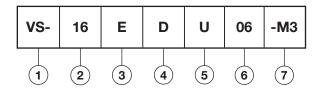
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (16 A)

3 - Circuit configuration:

E = single die

4 - D = SMPD package

Process type,

U = ultrafast recovery

6 - Voltage code (06 = 600 V)

7 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

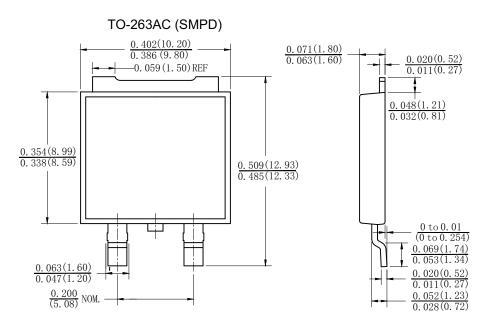
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-16EDU06-M3/I	2000	2000	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95604</u>				
Part marking information	www.vishay.com/doc?95566			
Packaging information	www.vishay.com/doc?88869			

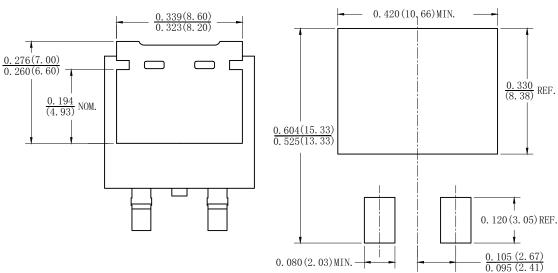


TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)



Mounting Pad Layout





Legal Disclaimer Notice

Vishay

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